

# Effect of Au thickness on magnetoresistance and Kerr spectra in Co/Au multilayers

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## Abstract

Magnetotransport and magneto-optical (MO) results on sputtered Co/Au multilayers at 300 K are reported. The thickness of Co layer was fixed at  $t_{\text{Co}} = 1$  nm while that of Au,  $t_{\text{Au}}$ , varied between 2.2 and 4 nm. Two giant-magnetoresistance (GMR) maxima were observed for  $t_{\text{Au}} \approx 2.4$  and 3.9 nm. For  $t_{\text{Au}} \approx 2.4$  nm the coercive field and switching fields are 7 and  $\pm 30$  Oe, respectively. MO Kerr hysteresis loops and spectra were measured in polar and longitudinal configurations. The loops provide evidence for the exchange coupling at the first GMR maximum and interface magnetic anisotropy for  $t_{\text{Au}} < 3$  nm. © 1999 Elsevier Science B.V. All rights reserved.

**Keywords:** Giantmagnetoresistance; Magneto-optics; Exchange coupling

The only system of sputtered TM/Au multilayers (TM = magnetic material) that exhibits oscillatory magnetoresistance (GMR) with a period of Au layer thickness  $t_{\text{Au}} \approx 1.2$  nm, was reported in untextured  $\text{Ni}_{81}\text{Fe}_{19}$ /Au films [1] while the most recent results for Co/Au sputtered MLs [2] are related with interesting magneto-optical (MO) properties. In the present study, Co/Au MLs grown by magnetron sputtering, were found to show a GMR oscillation with  $t_{\text{Au}}$ , and a sensible change in GMR ratio per unit field for the  $[\text{Co}(1 \text{ nm})/\text{Au}(2.4 \text{ nm})]_{30}$  composition. A series of magnetron sputtered  $[\text{Co}(1 \text{ nm})/\text{Au}(t_{\text{Au}})]_{30}$  MLs, nominal  $t_{\text{Au}} = 2.2, 2.4, 2.5, 3, 3.6, 3.9$  and 4 nm, has been deposited on Si(1 0 0) covered with 100 nm thick  $\text{SiN}_x$  buffer. The samples were characterized by X-ray diffraction and cross-section TEM. Sharp interfaces and an (1 1 1) preferred orientation are evident along the growth direction [3]. All the samples were studied by polar and longitudinal Kerr spectroscopy. The present paper reports on

magnetotransport (MR) and selected magneto-optical (MO) investigations.

The GMR measurements were performed at 300 K with the four-point-probe method, using a DC current of 1 mA for two directions of the applied field  $H$ : first with  $H$  lying in the film plane parallel to current ( $H \parallel I$ ) and then with  $H$  applied perpendicular to film ( $H \perp I$ ). All MR measurements were performed by first applying the maximum positive field  $H$  of 4 kOe and then completing the loop.

In Fig. 1 are shown the GMR curves for the  $[\text{Co}(1 \text{ nm})/\text{Au}(2.4 \text{ nm})]_{30}$  sample. In the ( $H \parallel I$ ) configuration the coercive field  $H_c$ , that is the field where the GMR maximum is observed, and the switching field  $H_s$ , that is the field where the GMR ratio approaches its lower value from both sides around  $H_c$  are 7 and  $\pm 30$  Oe, respectively. For comparison the observed values in the trilayers [4,5] are  $H_c \approx 500$  Oe and  $H_s \approx \pm 50$  Oe. This order of magnitude improvement of  $H_c$  brings the Co/Au MLs in the area of applications for GMR sensors.

In Fig. 2 are shown the MR ratio,  $[R_{\text{max}} - R(H_s)]/R(H_s)$ ,  $H_s$  and  $H_c$  as a function of  $t_{\text{Au}}$ , with  $H \parallel I$ . For  $t_{\text{Au}} > 2$  nm, two MR maxima were observed for  $t_{\text{Au}} \approx 2.4$  and 3.9 nm ( $\sim 10$  and 16 Au atomic planes),

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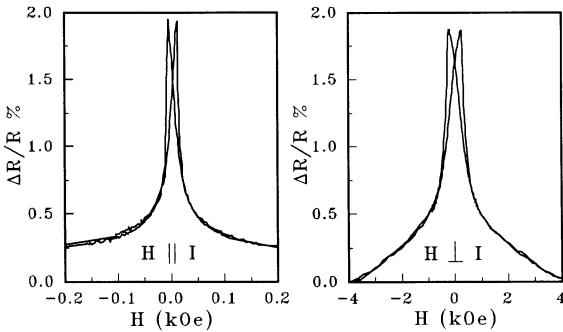


Fig. 1. GMR measurements in  $[\text{Co}(1 \text{ nm})/\text{Au}(2.4 \text{ nm})]_{30}$  MLs. On the left is plotted the GMR loop with  $H$  lying in the film plane parallel to current flow ( $H \parallel I$ ). On the right is plotted the transverse field ( $H \perp I$ ) GMR loop with  $H$  perpendicular to film.

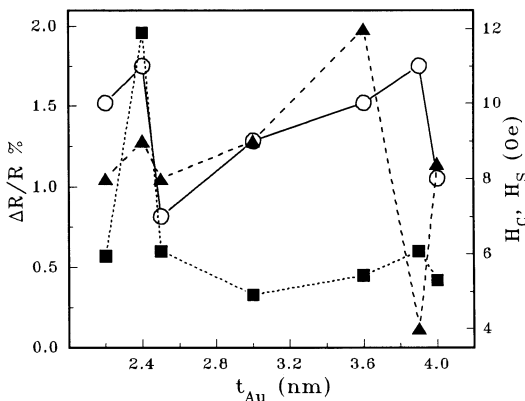


Fig. 2. Variation of the GMR ratio (squares),  $H_c$  (triangles) and  $H_s$  (circles) with  $t_{\text{Au}}$ , for  $H$  applied parallel to current flow direction.

respectively, attributed to the GMR effect. The existence of a residual GMR ratio about 0.4% in  $t_{\text{Au}}$  regions where the interlayer coupling is expected to be ferromagnetic is attributed to intralayer ('bulk') spin-dependent scattering [6]. These oscillations differ from those observed in epitaxial  $\text{Co}/\text{Au}(111)/\text{Co}$  trilayers [4] where GMR maxima occur for  $t_{\text{Au}} \approx 5, 9$  and  $14$  atomic planes (1.2, 2.1 and 3.3 nm). In the epitaxial trilayers the mean oscillation period is 4.5 atomic planes in agreement with the theoretical prediction [6]. A comparison  $t_{\text{Au}}$  values at the GMR maxima indicate that our first GMR peak, at  $\sim 10$  atomic planes of Au, is near the second GMR maximum of the trilayer in Ref. [4]. For  $t_{\text{Au}} \approx 2.4$  nm the GMR effect is mainly due to interfacial spin-dependent scattering while for thicker Au layers the increase of magnetic decoupling between adjacent Co layers enhances the contribution of intralayer spin-dependent scattering. The variation of  $H_c$  and  $H_s$  fields with  $t_{\text{Au}}$  (Fig. 2), obtained from the GMR curves with  $H \parallel I$ , are in agreement with the last argument.

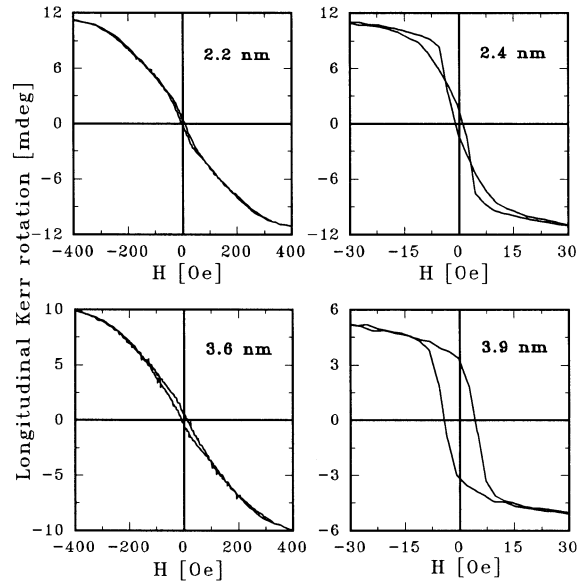


Fig. 3. Longitudinal Kerr-effect hysteresis loops for selected thicknesses  $t_{\text{Au}}$  at the photon energy of  $E = 2.76$  eV for a  $s$  polarized wave incident at  $45^\circ$ .

In Figs. 3 and 4 are shown the longitudinal Kerr-effect hysteresis loops. At the GMR minima ( $t_{\text{Au}} = 2.2$  and  $3.6$  nm) they reveal a significant magnetic anisotropy, that may be induced in the Co layers from a high concentration of step edges [7] located at the Co/Au interfaces due to surface reconstruction of the Au (111) planes. For  $t_{\text{Au}} = 2.4$  nm there is a manifold loop with insignificant residual magnetization, inferring coexistence of the so-called [8,6] 'bilinear' and 'biquadratic' interlayer coupling terms at the first GMR maximum. However, at the second GMR maximum there is a ferromagnetic loop, characteristic for a random distribution of Co magnetic moments (uncoupled layers) that contributes into 'bulk-like' spin scattering [6,7].

The polar loops confirmed the presence of the interface-induced anisotropy which reduces the saturation field below 3 kOe, while the coercive field varies between 10 and 65 Oe. The Kerr spectra show a distinct Au plasma edge peak centered near 2.5 eV. A narrowing and reduction in the amplitude of the peak is observed by increasing  $t_{\text{Au}}$ . These trends were reproduced by computer simulations [9] with the experimental amplitudes about 50% smaller. This difference can be attributed to extended intralayer and/or interface disorder, located mainly at the ferromagnetic Co layers, and to changes in Au electronic states induced by adjacent Co layers.

In summary, it is shown that magnetron sputtered Co/Au MLs with (111) texturing display GMR effects, for  $t_{\text{Au}} > 2$  nm, with small saturation and switching

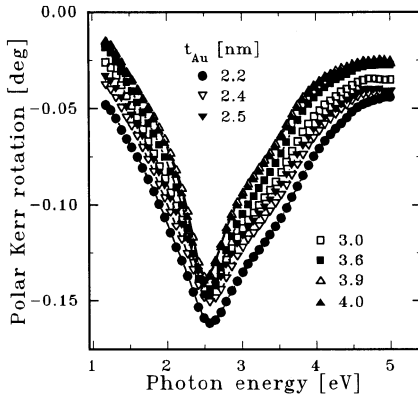


Fig. 4. Saturated polar Kerr rotation spectra of  $[\text{Co}(1 \text{ nm})/\text{Au}(t_{\text{Au}} \text{ nm})]_{30}$  multilayers with a fixed Co thickness,  $t_{\text{Co}} = 1 \text{ nm}$  and  $t_{\text{Au}}$  between 2.2 and 4.0 nm.

fields. Static deposition of the constituents with low rates, on  $\text{SiN}_x$  buffer layer, seems to enable the development of a considerable fraction of faults in the atomic packing of Co layers along the growth direction. Thus, the observed differences in magnetotransport properties, between the examined here Co/Au MLs and those reported by now, can be attributed to the development of a specific microstructure in the magnetic layers. The practical advantage of the prepared Co/Au MLs is the achievement of a low  $H_c$ , obtained under deposition conditions requiring less

demand on the growth process, that makes possible their use in GMR sensors.

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## References

- [1] S.S.P. Parkin, T. Rabeadeau, *Appl. Phys. Lett.* 68 (1996) 1162.
- [2] Y. Liu, Z.S. Shan, D.J. Sellmeyer, *J. Appl. Phys.* 81 (1997) 5061.
- [3] S. Stavroyiannis, C. Christides, Th. Kehagias, Ph. Komninou, Th. Karakostas, D. Niarchos, *J. Appl. Phys.*, submitted.
- [4] V. Grolier, D. Renard, B. Bartelien, P. Beauvillian, C. Chappert, C. Dupas, J. Ferré, M. Galtier, E. Kolb, M. Mulloy, J.P. Renard, P. Veilet, *Phys. Rev. Lett.* 71 (1993) 3023.
- [5] E. Velu, C. Dupas, D. Renard, J.P. Renard, J. Seiden, *Phys. Rev. B* 37 (1988) 668.
- [6] B. Heinrich, J.A.C. Bland (Eds.), *Ultrathin Magnetic Structures II*, Springer, Berlin, 1994 Chapter 2.
- [7] M. Viret, D. Vingoies, D. Cole, J.M.D. Coey, W. Allen, D.S. Daniel, J.F. Gregg, *Phys. Rev. B* 53 (1996) 8464.
- [8] A. Fuß, S. Demokritov, P. Grunberg, W. Zinn, *J. Magn. Mater.* 103 (1992) L221.
- [9] M. Nývlt, Ph.D. Thesis, Charles University, Prague, 1996.